CRYSTAL OSCILLATOR (Programmable)
OUTPUT: CMOS

Pb Free　RoHS Compliant

Product Number
SG-8200CJ: X1G006211xxxx16
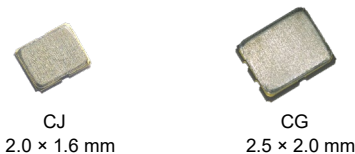**SG-8200CG: X1G006201xxxx16**

SG-8200 series

- Frequency range　　　　　　: 1.2 MHz to 170 MHz
- Supply voltage　　　　　　　: 1.62 V to 3.63 V
- Function　　　　　　　　　　: Output enable (OE/$\overline{OE}$) or Standby ($\overline{ST}$/ST)
- Frequency tolerance, operating temperature**:**
　　　　　　　　　　　　　　　±50 × 10⁻⁶ (-40 °C to +125 °C)
- PLL technology to enable setting any output frequency

CJ
2.0 × 1.6 mm

CG
2.5 × 2.0 mm

▉ Specifications (characteristics)

Item	Symbol	Specifications			Conditions/Remarks	
Supply voltage	V_{CC}	1.80 V Typ.	2.50 V Typ.	3.30 V Typ.		
		1.62 V to 1.98 V	2.25 V to 2.75 V	2.97 V to 3.63 V		
Output frequency range	f_O	1.2 MHz to 170 MHz				
Storage temperature range	T_stg	-55 °C to +150 °C			Storage as single product.	
Operating temperature range	T_use	J: -40 °C to +125 °C				
Frequency tolerance[*1]	f_tol	J: ±50 × 10⁻⁶			T_use = -40 °C to +125 °C	
Current consumption	I_{CC}	5.2 mA Typ.	5.4 mA Typ.	5.6 mA Typ.	1.2 MHz ≤ f_O ≤ 25 MHz	No load, Rise/Fall time: Default
		7.0 mA Max.	7.2 mA Max.	7.5 mA Max.		
		5.4 mA Typ.	5.7 mA Typ.	6.1 mA Typ.	25 MHz < f_O ≤ 50 MHz	
		7.3 mA Max.	7.6 mA Max.	8.1 mA Max.		
		5.7 mA Typ.	6.3 mA Typ.	7.0 mA Typ.	50 MHz < f_O ≤ 75 MHz	
		7.7 mA Max.	8.2 mA Max.	9.1 mA Max.		
		6.2 mA Typ.	6.9 mA Typ.	7.9 mA Typ.	75 MHz < f_O ≤ 100 MHz	
		8.2 mA Max.	9.1 mA Max.	10.4 mA Max.		
		6.9 mA Typ.	7.9 mA Typ.	9.1 mA Typ.	100 MHz < f_O ≤ 125 MHz	
		9.4 mA Max.	10.7 mA Max.	12.4 mA Max.		
		7.8 mA Typ.	9.2 mA Typ.	11.2 mA Typ.	125 MHz < f_O ≤ 170 MHz	
		10.4 mA Max.	12.4 mA Max.	15.0 mA Max.		
Output disable current	I_dis	5.0 mA Typ.	5.0 mA Typ.	5.1 mA Typ.	OE = GND, $\overline{OE}$ = V_{CC}	
		7.2 mA Max.	7.3 mA Max.	7.4 mA Max.		
Standby current	I_std	0.3 µA Typ.	0.3 µA Typ.	0.5 µA Typ.	$\overline{ST}$ = GND, ST = V_{CC}	
		15.0 µA Max.	15.0 µA Max.	15.0 µA Max.		
Symmetry	SYM	45 % to 55 %			50 % V_{CC} Level, L_CMOS ≤ 15 pF	

Item	Symbol	Specifications	Rise/Fall time		I_{OH}	I_{OL}
			Default 'A' Option[*2]	Other Options		
Output voltage (DC characteristics)	V_{OH}	90 % V_{CC} Min.	fo > 125 MHz	B: Faster	-2.0 mA	2.0 mA
			75 MHz < fo ≤ 125 MHz	C: Fast	-1.0 mA	1.0 mA
	V_{OL}	10 % V_{CC} Max.	50 MHz < fo ≤ 75 MHz	D: Slow	-0.5 mA	0.5 mA
			fo ≤ 50 MHz	E: Slower	-0.2 mA	0.2 mA

Item	Symbol	Specifications	Conditions/Remarks
Output load condition	L_CMOS	15 pF Max.	
Input voltage	V_{IH}	70 % V_{CC} Min.	Pin 1
	V_{IL}	30 % V_{CC} Max.	

Item	Symbol	Specifications	Default 'A' Option[*2]	Other Options	
Rise/Fall time	tr/tf	-			20 % - 80 % V_{CC}, L_CMOS = 15 pF
		2.0 ns Max.	fo > 125 MHz	B: Faster	
		2.5 ns Max.	75 MHz < fo ≤ 125 MHz	C: Fast	
		4.0 ns Max.	50 MHz < fo ≤ 75 MHz	D: Slow	
		6.0 ns Max.	fo ≤ 50 MHz	E: Slower	

Item	Symbol	Specifications	Conditions/Remarks
Output disable time (OE) Output disable time (ST)	tstp_oe tstp_st	1 µs Max.	Measured from the time OE or $\overline{ST}$ pin crosses 30 % V_{CC} or measured from the time $\overline{OE}$ or ST pin crosses 70 % V_{CC}
Output enable time (OE)	tsta_oe	100 ns + 2 clock cycle Max.	Measured from the time OE pin crosses 70 % V_{CC} or measured from the time $\overline{OE}$ pin crosses 30 % V_{CC}
Output enable time (ST)	tsta_st	3 ms Max.	Measured from the time $\overline{ST}$ pin crosses 70 % V_{CC} or measured from the time ST pin crosses 30 % V_{CC}
Start-up time	t_str	3 ms Max.	Measured from the time V_{CC} reaches its rated minimum value, 1.62 V
Phase Jitter	t_{PJ}	1.2 ps Typ.	fo = 25 MHz, Offset frequency: 12 kHz to 5 MHz
		1.2 ps Typ.	fo = 50 MHz, Offset frequency: 12 kHz to 20 MHz
		1.2 ps Typ.	fo = 75 MHz, Offset frequency: 12 kHz to 20 MHz
		1.2 ps Typ.	fo = 100 MHz, Offset frequency: 12 kHz to 20 MHz
		1.1 ps Typ.	fo = 125 MHz, Offset frequency: 12 kHz to 20 MHz
		1.4 ps Typ.	fo = 150 MHz, Offset frequency: 12 kHz to 20 MHz
		1.5 ps Typ.	fo = 170 MHz, Offset frequency: 12 kHz to 20 MHz
Frequency aging	f_age	This is included in frequency tolerance specification.	+25 °C, first year

*1 Frequency tolerance includes initial frequency tolerance, temperature variation, supply voltage variation, reflow drift, load drift and aging (+25 °C, 1 year).
*2 Default 'A' Rise/Fall time and I_{OH}/I_{OL} are dependent on programmed frequency.

Pin description

Pin	Name	I/O type		Function
1	OE	Input	Output Enable	High[*1] or Open: Specified frequency output from OUT pin
				Low: OUT pin is low (pull down with 500 kΩ), only output driver is disabled.
	$\overline{OE}$	Input	Output Enable	Low[*2] or Open: Specified frequency output from OUT pin
				High: OUT pin is low (pull down with 500 kΩ), only output driver is disabled.
	$\overline{ST}$	Input	Standby	High[*1 *3]: Specified frequency output from OUT pin
				Low: OUT pin is low (pull down with 500 kΩ), Device goes to standby mode. Supply current reduces to the least as I_std.
	ST	Input	Standby	Low[*2 *3]: Specified frequency output from OUT pin
				High: OUT pin is low (pull down with 500 kΩ), Device goes to standby mode. Supply current reduces to the least as I_std.
2	GND	Power	Ground	
3	OUT	Output	Clock output	
4	V_{CC}	Power	Power supply	

*1 If fixing it at High, please connect to V_{CC} directly.
*2 If fixing it at Low, please connect to GND directly.
*3 If necessary to use Open, please select Output Enable function.

Product Name

SG-8200CJ 170.000000MHz T J J P A
a   b   c   d e f g h

a: Model   b: Package type
c: Frequency   d: Supply voltage (T: 1.8 V to 3.3 V Typ.)
e: Frequency tolerance   f: Operating temperature
g: Function   h: Rise/Fall time

b: Package type	
CJ	2.0 mm × 1.6 mm
CG	2.5 mm × 2.0 mm

e: Frequency tolerance / f: Operating temperature	
JJ	±50 x 10[-6] / -40 °C to +125 °C

g: Function	
P	Output Enable (OE)
Q	Output Enable ($\overline{OE}$)
S	Standby ($\overline{ST}$)
T	Standby (ST)

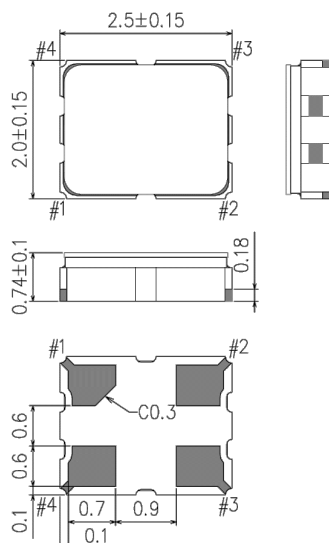| h: Rise/Fall time	
A	Default
B	Faster
C	Fast
D	Slow
E	Slower

External dimensions   (Unit: mm)
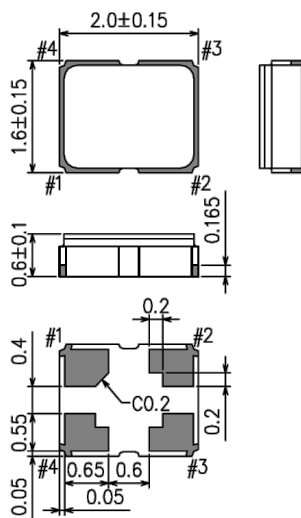
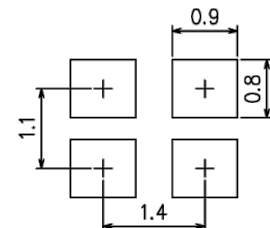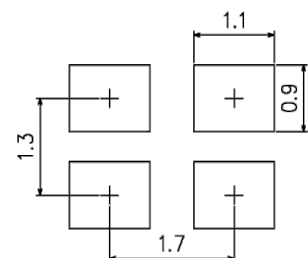SG-8200CJ   SG-8200CG

Footprint (Recommended)   (Unit: mm)

SG-8200CJ

SG-8200CG

■Notes:

In order to achieve optimum jitter performance, the 0.01 µF to 0.1 µF capacitor between V_{CC} and GND should be placed. It is also recommended that the capacitors are placed on the device side of the PCB, as close to the device as possible and connected together with short wiring pattern.

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